

iscN-Channel MOSFET Transistor

IRFP250

RDS(• Enhand Vth = • 100% a • Minimu perform • DESCF • Switchi	ain-source on-resistance: ON) $\leq 85m\Omega$ @V _{GS} =10V cement mode: = 2.0 to 4.0V (VDS = 10 V, ID=0.25m avalanche tested Im Lot-to-Lot variations for robust d nance and reliable operation RITION ng Voltage Regulators LUTE MAXIMUM RATINGS(T _a =25	G(1) G(1) G(1) S(3) pin 1.Gate 2.Drain 3.Source 1 2 3 TO-247 package		
SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	200	v	
V _{GS}	Gate-Source Voltage	±20	v	
lD	Drain Current-Continuous	30	A	
IDM	Drain Current-Single Pulsed	120	A	
P _D	Total Dissipation @T _c =25°C	190	w	MM DIM MIN MAX A 19.80 20.20
Tj	Max. Operating Junction Temperature	-55~150	°C	B 15.40 15.80 C 4.90 5.10 D 0.90 1.10
T _{stg}	Storage Temperature	-55~150	°C	E 1.40 1.60 F 1.90 2.10 G 10.80 11.00
THERMAL CHARACTERISTICS				H 2.40 2.60 J 0.50 0.70 K 19.50 20.50
SYMBOL	PARAMETER	МАХ	UNIT	P 3.90 4.10 Q 3.30 3.50
Rth(ch-c)	Channel-to-case thermal resistance	0.65	°C/W	U 5.20 5.40 V 2.90 3.10

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isc website: www.iscsemi.cn



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ELECTRICAL CHARACTERISTICS

$T_{\texttt{C}}\text{=}25^{\circ}\!\!\!\mathbb{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	200			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = 10V; I _D =0.25mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =18A			85	mΩ
lgss	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V			±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =200V; V _{GS} = 0V V _{DS} =160V; V _{GS} = 0V;T _J =125°C			25 250	uA
V _{SDF}	Diode forward voltage	I _{DR} =30A, V _{GS} = 0 V			2.0	V

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